



CRYSTAL OSCILLATOR (SPXO)

OUTPUT : CMOS, TTL

SG-615 series

SG-531 / SG-51 series

- Frequency range : 1.025 MHz to 135 MHz
- Supply voltage : 3.3 V Typ. / 5.0 V Typ.
- Function : Output enable(OE) or Standby(\overline{ST})
- Pin compatible with full-size metal can. (SG-51 series)
- Pin compatible with half-size metal can. (SG-531 series)



Product Number (please contact us)

SG-615 : Q33615xx2xxxx00

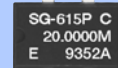
SG-531 : Q32531xx2xxxx00

SG-51 : Q32510xx2xxxx00



Actual size

SG-615



SG-531



SG-51



Specifications (characteristics)

| Item | Symbol | Specifications | | Conditions / Remarks |
|------------------------------|-------------|--|------------------------------------|--|
| | | SG-615P SG-531P SG-51P | SG-615PTJ SG-531PTJ SG-51PTJ | |
| Output frequency range | f_o | 1.025 MHz to 26 MHz | 26.001 MHz to 66.667 MHz | Please contact us about available frequencies. |
| Supply voltage | V_{CC} | 5.0 V ± 0.5 V | | |
| Storage temperature | T_{stg} | -55 °C to +125 °C | | Storage as single product. |
| Operating temperature | T_{use} | -20 °C to +70 °C | | |
| Frequency tolerance | f_{tol} | B ¹ : $\pm 50 \times 10^{-6}$, C: $\pm 100 \times 10^{-6}$ | | -20 °C to +70 °C |
| Current consumption | I_{CC} | 23 mA Max. | 35 mA Max. | No load condition |
| Disable current | I_{dis} | 12 mA Max. | 28 mA Max. | OE=GND |
| Symmetry | SYM | 40 % to 60 % | — | CMOS load: 50 % V_{CC} level |
| | | 40 % to 60 % | 45 % to 55 % | TTL load: 1.4 V level |
| Output voltage | V_{OH} | $V_{CC}-0.4$ V Min. | | $I_{OH}=-400 \mu A$ |
| | V_{OL} | 0.4 V Max. | | $I_{OL}=16$ mA(P)/ 8 mA(PTJ) |
| Output load condition (TTL) | L_{TTL} | 10 TTL Max. | 5 TTL Max. | $L_{CMOS} \leq 15$ pF |
| Output load condition (CMOS) | L_{CMOS} | 50 pF Max. | — | |
| Input voltage | V_{IH} | 2.0 V Min. | 3.5 V Min. | $I_{IH}=1 \mu A$ Max. (OE= V_{CC}) |
| | V_{IL} | 0.8 V Max. | 1.5 V Max. | $I_{IL}=-100 \mu A$ Min. (OE=GND), PTJ: $I_{IL}=-500 \mu A$ Min. (OE=GND) |
| Rise time / Fall time | t_r / t_f | 8 ns Max. | — | CMOS load: 20 % V_{CC} to 80 % V_{CC} level |
| Start-up time | t_{str} | 4 ms Max. | 10 ms Max. | TTL load: 0.4 V to 2.4 V level |
| Frequency aging | f_{aging} | $\pm 5 \times 10^{-6}$ / year Max. | | Time at minimum supply voltage to be 0 s |
| | | | | +25 °C, $V_{CC}=5.0$ V, First year |

*1 "B" tolerance will be available up to 55 MHz.

Specifications (characteristics)

| Item | Symbol | Specifications | | | Conditions / Remarks |
|------------------------|-------------|---|------------------------|--------------------------|--|
| | | SG-615PCG SG-531PCG | SG-615SCG SG-531SCG | SG-615PCN | |
| Output frequency range | f_o | 1.500 MHz to 26.000 MHz | | 26.001 MHz to 66.667 MHz | Please contact us about available frequencies. |
| Supply voltage | V_{CC} | 2.7 V to 3.6 V | | 3.0 V to 3.6 V | |
| Storage temperature | T_{stg} | -55 °C to +125 °C | | | Storage as single product. |
| Operating temperature | T_{use} | -40 °C to +85 °C | | | |
| Frequency tolerance | f_{tol} | B: $\pm 50 \times 10^{-6}$ C: $\pm 100 \times 10^{-6}$ M: $\pm 100 \times 10^{-6}$ | | | -20 °C to +70 °C -40 °C to +85 °C |
| Current consumption | I_{CC} | 12 mA Max. | | 20 mA Max. | No load condition |
| Disable current | I_{dis} | 10 mA Max. | — | 10 mA Max. | OE=GND (PCG, PCN) |
| Stand-by current | I_{std} | — | 50 μA Max. | — | \overline{ST} =GND (SCG) |
| Symmetry | SYM | 45 % to 55 % | | — | 50 % V_{CC} level, L_{CMOS} =Max. |
| | | | | | |
| Output voltage | V_{OH} | $V_{CC}-0.4$ V Min. | | $V_{CC}-0.4$ V Min. | $I_{OH}=-8$ mA |
| | V_{OL} | 0.4 V Max. | | 0.4 V Max. | $I_{OL}=8$ mA |
| Output load condition | L_{CMOS} | 25 pF Max. | | 15 pF Max. | |
| Input voltage | V_{IH} | 70 % V_{CC} Min. | | 70 % V_{CC} Min. | OE Terminal or \overline{ST} Terminal |
| | V_{IL} | 20 % V_{CC} Max. | | 30 % V_{CC} Max. | |
| Rise time / Fall time | t_r / t_f | 4 ns Max. | | | 20 % V_{CC} to 80 % V_{CC} level, $L_{CMOS} \leq$ Max. |
| Start-up time | t_{str} | 12 ms Max. | | 10 ms Max. | $t=0$ at 90 % V_{CC} |
| Frequency aging | f_{aging} | $\pm 5 \times 10^{-6}$ / year Max. | | | +25 °C, $V_{CC}=3.3$ V, First year |



Specifications (characteristics)

| Item | Symbol | Specifications | | | Conditions / Remarks |
|------------------------------|--------------------|--|------------------------------------|------------------------------------|--|
| | | SG-615PTW / STW SG-531PTW / STW | SG-615PHW / SHW SG-531PHW / SHW | SG-615PCW / SCW SG-531PCW / SCW | |
| Output frequency range | f ₀ | 55.001 MHz to 135.000 MHz | | | Please contact us about available frequencies. |
| Supply voltage | V _{CC} | 5.0 V ±0.5 V | | | |
| Storage temperature | T _{stg} | -55 °C to +125 °C | | | Storage as single product. |
| Operating temperature | T _{use} | -20 °C to +70 °C | | | |
| Frequency tolerance | f _{tol} | B: ±50 × 10 ⁻⁶ , C ¹ : ±100 × 10 ⁻⁶ | | | -20 °C to +70 °C |
| | | — | | | -40 °C to +85 °C |
| Current consumption | I _{CC} | 45 mA Max. | | | No load condition(Max. frequency range) |
| Disable current | I _{dis} | 30 mA Max. | | | |
| Stand-by current | I _{std} | 50 μA Max. | | | OE=GND (PTW,PHW,PCW) |
| Symmetry | SYM | — | | | ST =GND (STW,SHW,SCW) |
| | | 40 % to 60 % | | | 50 % V _{CC} level, L _{CMOS} =Max. |
| Output voltage | V _{OH} | V _{CC} -0.4 V Min. | | | 1.4 V level, L _{CMOS} =Max. |
| | V _{OL} | 0.4 V Max. | | | I _{OH} =-16 mA(PTW,STW,PHW,SHW), -8 mA(PCW,SCW) |
| Output load condition (TTL) | L _{TTL} | 5 TTL Max. | — | — | I _{OL} = 16 mA(PTW,STW,PHW,SHW), 8 mA(PCW,SCW) |
| Output load condition (CMOS) | L _{CMOS} | 15 pF Max. | | | f ₀ ≤ 90 MHz , Max.supply voltage |
| Input voltage | V _{IH} | 2.0 V Min. | | | Max.frequency , Max.supply voltage |
| | V _{IL} | 0.8 V Max. | | | |
| Rise time / Fall time | tr / tr | 70 % V _{CC} Min. | | | OE Terminal or ST Terminal |
| | | 20 % V _{CC} Max. | | | |
| Start-up time | t _{str} | — | | | 20 % V _{CC} to 80 % V _{CC} level, L _{CMOS} ≤ Max. |
| | | 4 ns Max. | | | |
| Frequency aging | f _{aging} | 4 ns Max. | | | 0.4 V to 2.4 V level |
| | | — | | | |
| Start-up time | t _{str} | 10 ms Max.. | | | Time at minimum supply voltage to be 0 s |
| Frequency aging | f _{aging} | ±5 × 10 ⁻⁶ / year Max. | | | |
| | | | | | +25 °C, V _{CC} =5.0 V / 3.3 V, First year |

*2 "C" tolerance : $f_0 \geq 66.667$ MHz (PTW,STW,PHW,SHW)

Product Name SG-615 P C G 20.000000MHz C

(Standard form)

① ②③ ④ ⑤

①Model ②Function (P: Output enable, S:Standby)

③Supply voltage ④Frequency

⑤Frequency tolerance

③Supply voltage

C 3.3 V Typ.

T,H 5.0 V Typ.

Blank 5.0 V Typ.

⑤Frequency tolerance

B $\pm 50 \times 10^{-6}$ / -20 to +70 °CC $\pm 100 \times 10^{-6}$ / -20 to +70 °CM $\pm 100 \times 10^{-6}$ / -40 to +85 °C

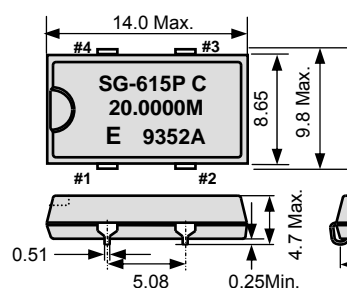
External dimensions

(Unit:mm)

Footprint (Recommended)

(Unit:mm)

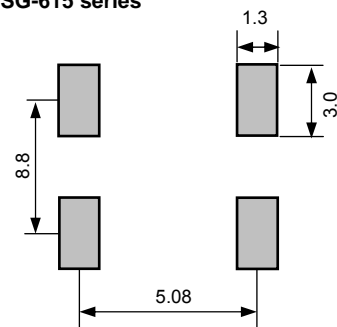
● SG-615 series



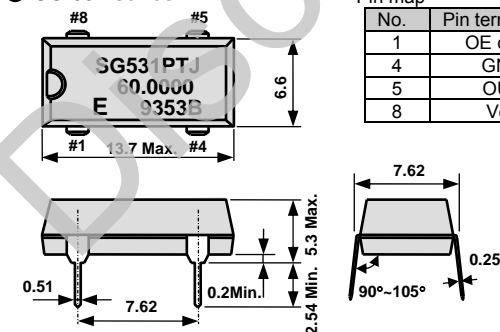
Pin map

| Pin | Connection |
|-----|------------|
| 1 | OE or ST |
| 2 | GND |
| 3 | OUT |
| 4 | Vcc |

● SG-615 series



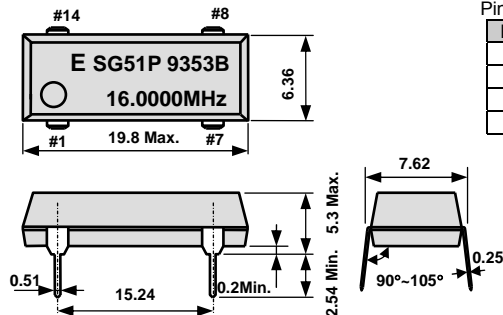
● SG-531 series



Pin map

| No. | Pin terminal |
|-----|--------------|
| 1 | OE or ST |
| 4 | GND |
| 5 | OUT |
| 8 | Vcc |

● SG-51 series



Pin map

| Pin | Connection |
|-----|------------|
| 1 | OE or ST |
| 7 | GND |
| 8 | OUT |
| 14 | Vcc |

Note.

OE pin (P,PTJ,PTW,PHW,PCW,PCN,PCG)

OE pin = "H" or "open" : Specified frequency output.

OE pin = "L" : Output is high impedance.

ST pin (STW, SHW, SCW,SCG)

ST pin = "H" or "open" : Specified frequency output.

ST pin = "L" : Output is low level

(weak pull - down), oscillation stops.

To maintain stable operation, provide a 0.01 μ F to 0.1 μ F by-pass capacitor at a location as near as possible to the power source terminal of the crystal product (between Vcc - GND).

PROMOTION OF ENVIRONMENTAL MANAGEMENT SYSTEM CONFORMING TO INTERNATIONAL STANDARDS

At Seiko Epson, all environmental initiatives operate under the Plan-Do-Check-Action (PDCA) cycle designed to achieve continuous improvements. The environmental management system (EMS) operates under the ISO 14001 environmental management standard.

All of our major manufacturing and non-manufacturing sites, in Japan and overseas, completed the acquisition of ISO 14001 certification.

ISO 14000 is an international standard for environmental management that was established by the International Standards Organization in 1996 against the background of growing concern regarding global warming, destruction of the ozone layer, and global deforestation.





WORKING FOR HIGH QUALITY

In order provide high quality and reliable products and services than meet customer needs,

Seiko Epson made early efforts towards obtaining ISO9000 series certification and has acquired ISO9001 for all business establishments in Japan and abroad. We have also acquired ISO/TS 16949 certification that is requested strongly by major automotive manufacturers as standard.

ISO/TS16949 is the international standard that added the sector-specific supplemental requirements for automotive industry based on ISO9001.

► Explanation of the mark that are using it for the catalog

| | |
|---|---|
|  | ► Pb free. |
|  | ► Complies with EU RoHS directive. *About the products without the Pb-free mark. Contains Pb in products exempted by EU RoHS directive. (Contains Pb in sealing glass, high melting temperature type solder or other.) |
|  | ► Designed for automotive applications such as Car Multimedia, Body Electronics, Remote Keyless Entry etc. |
|  | ► Designed for automotive applications related to driving safety (Engine Control Unit, Air Bag, ESC etc). |

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